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N-Channel 200 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (mΩ) (Typ.)	I _D (A)	Q _g (Typ.)			
200	7.3 at V _{GS} = 10 V	155	86 nC			

TO-247 Pin Configuration

FEATURES

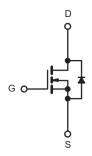
- DT-Trench II Power MOSFET
- 100 % R_g and UIS tested
- Extremely Low R_{DS(ON)}

RoHS COMPLIANT

APPLICATIONS

- Synchronous Rectification
- Motor Drives and Uninterruptible Power Supplies





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V _{DS}	200	V			
Gate-Source Voltage	V _{GS}	± 20	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \			
Continuous Drain Current /T 150 °C)	T _C = 25 °C	I _D	155	^		
Continuous Drain Current (T _J = 150 °C)	T _C = 100 °C	D D	108			
Pulsed Drain Current (t = 100 μs)	I _{DM}	620	Α			
Avalanche Current	L = 0.1 mH	I _{AS}	150			
Single Avalanche Energy ^a	L = 0.1 IIIII	E _{AS}	818	mJ		
Manipular Davies Dispiration 8	T _C = 25 °C	В	407 ^b	W		
Maximum Power Dissipation ^a	T _C = 100 °C	$ P_D$	92.8 ^b]		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER			LIMIT	UNIT		
Junction-to-Ambient (PCB Mount) °	t ≤ 10 s	R _{thJA}	60	°C/W		
Junction-to-Case (Drain)	Steady State	R _{thJC}	0.5	- C/VV		

Notes

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.
- c. When mounted on 1" square PCB (FR4 material).



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				'		
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	200	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	2	-	4	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
Zero Gate Voltage Drain Current		V _{DS} = 200 V, V _{GS} = 0 V		-	1	
	I _{DSS}	V _{DS} = 160 V, V _{GS} = 0 V, T _J = 100 °C	-	-	50	μA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	155	-	-	Α
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 30 A	-	7.3	8.5	mΩ
Forward Transconductance ^a	9 _{fs}	V _{DS} = 5 V, I _D = 30 A	-	65	-	S
Dynamic ^b				•		
Input Capacitance	C _{iss}		-	9513	-	pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 100 V, f = 1 MHz	-	1103	-	
Reverse Transfer Capacitance	C _{rss}		-	20	-	
Total Gate Charge ^c	Qg		-	86	-	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	-	35	-	nC
Gate-Drain Charge ^c	Q _{gd}		-	11	-	
Gate Resistance	R_g	f = 1 MHz	-	1.5	-	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	29	-	
Rise Time ^c	t _r	$V_{DD} = 100 \text{ V}, I_D = 30 \text{ A}, R_g = 6 \Omega$	-	60	-	ns
Turn-Off Delay Time ^c	t _{d(off)}	V _{GS} = 10 V	-	79	-	
Fall Time ^c	t _f		-	19	-	
Drain-Source Body Diode Ratings and	Characterist	tics ^b (T _C = 25 °C)				
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C	-	-	155	Α
Pulsed Current (t = 100 µs)	I _{SM}		-	-	620	Α
Forward Voltage ^a	V _{SD}	I _F = 30 A, V _{GS} = 0 V	-	-	1.25	٧
Reverse Recovery Time	t _{rr}	L = 30 A di/dt = 100 A/::=	-	106	-	ns
Reverse Recovery Charge	Q_{rr}	I _F = 30 A, di/dt = 100 A/μs	_	339	_	nC

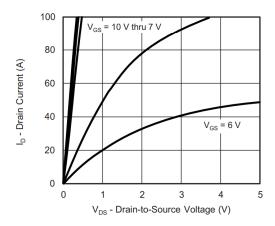
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

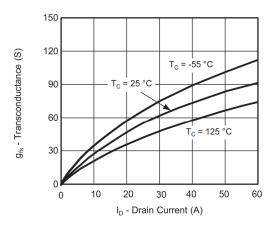
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



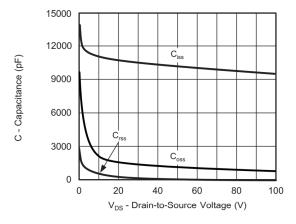
TYPICAL CHARACTERISTICS ($T_A = 25 \, ^{\circ}\text{C}$, unless otherwise noted)



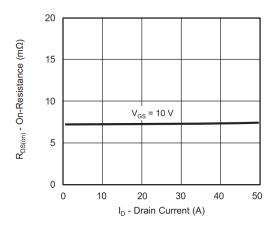
Output Characteristics



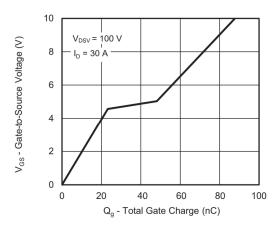
Transconductance



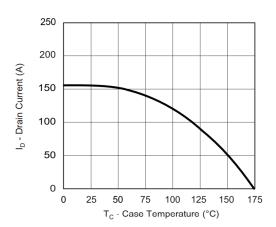
Capacitance



On-Resistance vs. Drain Current



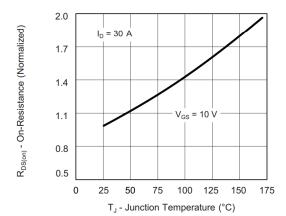
Gate Charge



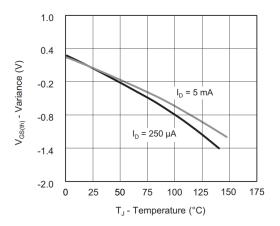
Current De-Rating



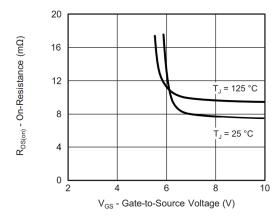
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



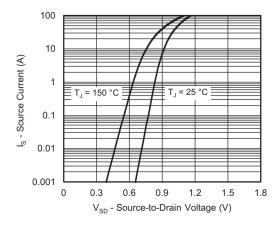
On-Resistance vs. Junction Temperature



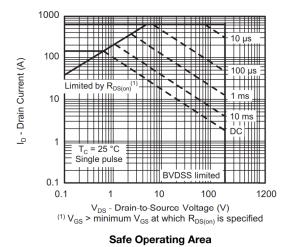
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage



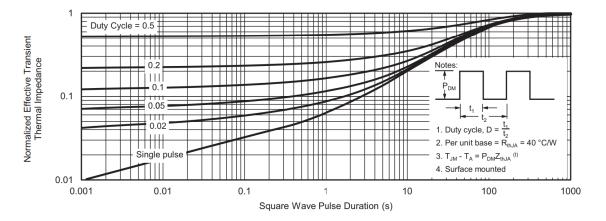
Source Drain Diode Forward Voltage



4



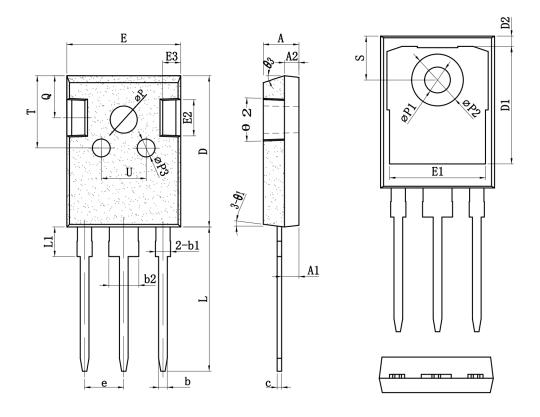
THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



TO-247_3L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	4.60	5.00	5.40	e	2.10	5.44	5.70
A1	2.10	2.41	2.70	L	19.00	19.98	21.00
A2	1.70	2.00	2.30	L1	1	-	4.50
b	1.00	1.20	1.40	ФР	3.30	3.70	4.00
b1	1.80	2.10	2.40	ФР1	3.25	3.55	3.85
b2	2.80	3.10	3.40	ФР2	6.80	7.18	7.60
С	0.45	0.60	0.75	ФР3	2.30	2.50	3.30
D	19.00	21.00	23.00	Q	5.50	5.80	6.30
D1	16.00	16.55	17.00	S	5.60	6.15	6.30
D2	0.95	1.20	1.45	T	9.50	10.00	10.50
Е	15.70	15.80	16.50	U	6.00	-	8.00
E1	12.80	13.25	13.70	θ1	5°	7°	9°
E2	4.20	5.00	5.30	θ2	1°	3°	5°
E3	2.20	2.50	2.80	θ3	13°	15°	17°





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